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LH5164A-10LF 64K Static RAM

(Model Number: LH516A2)

Spec. Issue Date: October 22, 2004

Spec No: EL16X051



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ISSUE:	Oct.	22.	200)4		

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Product Type	64k SRAM
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Product Development Dept. 3
System Flash Memory Division
Integrated Circuits Group
SHARP CORPORATION



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 - (1) The products covered herein are designed and manufactured for the following application areas. When using the products covered herein for the equipment listed in Paragraph (2), even for the following application areas, be sure to observe the precautions given in Paragraph (2). Never use the products for the equipment listed in Paragraph (3).
 - · Office electronics
 - · Instrumentation and measuring equipment
 - · Machine tools
 - · Audiovisual equipment
 - · Home appliances
 - · Communication equipment other than for trunk lines
 - (2) Those contemplating using the products covered herein for the following equipment which demands high reliability, should first contact a sales representative of the company and then accept responsibility for incorporating into the design fail-sale operation, redundancy, and other appropriate measures for ensuring reliability and safety of the equipment and the overall system.
 - · Control and safety devices for airplanes, trains, automobiles, and other transportation equipment
 - · Mainframe computers
 - · Traffic control systems
 - · Gas leak detectors and automatic cutoff devices
 - · Rescue and security equipment
 - · Other safety devices and safety equipment, etc.
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- Please direct all queries regarding the products covered herein to a sales representative of the company.



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1. Decription

The L H 5 1 6 4 A - 1 0 L F is a static RAM organized as 8, 1 9 2 \times 8 bit with provides low-power standby mode.

It is fabricated using silicon-gate CMOS process technology.

 \bigcirc 2 8 pin DIP (DIP 28-P-600) plastic package

Features

OAccess Time		100 ns	(Max.)
O0perating current		4 5 mA	(Max.)
		10 mA	(Max. trc, twc=1 μ s)
OStandby current		1.0 μΑ	(Max.)
OData retention current		0.2 μΑ	(Max. $V_{CCDR} = 3 \text{ V, } Ta = 25\%$)
OSingle power supply	5	$V \pm 1~0~\%$	
Operating temperature	$\cdots -10$	℃to+70℃	
OFully static operation			
OThree state output			
ONot designed or rated as radiat	ion hardened		

2. Pin Configuration

OP-type bulk silicon

				-
NC		1 🔾	28	□ Vcc
A_{12}		2	27	WE
А 7		3	26	CE 2
Аб		4	25	□ A 8
A 5		5	24	□ A 9
A 4		6	23	□ A ₁₁
Аз		7	22	OE
A ₂		8	21	A 10
A_1		9	20	CE ₁
Αo		10	19	I /O 8
I /O 1		11	18	□ I /O 7
I /O 2		12	17	□ I /O 6
I /O 3	\Box	13	16	I/O5
GND		14	15	□ I /O₄
	ŧ			i

Pin Name	Function
	Address inputs
A 0 to A 12	Address inputs
C E 1/C E 2	Chip enable
WE	Write enable
OE	Output enable
I /O 1 to I /O 8	Data inputs/outputs
V cc	Power supply
GND	Ground
NC	Non connection

(Top View)

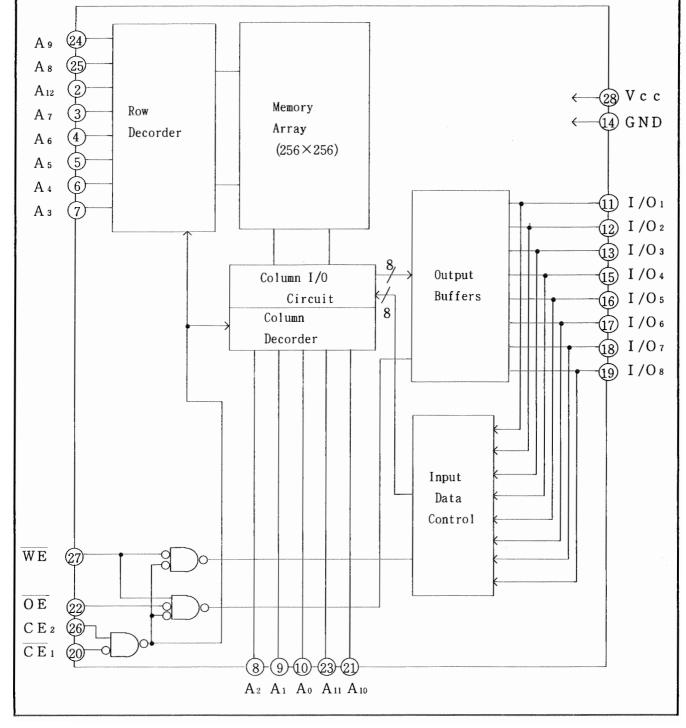
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3. Truth Table

CEı	CE2	WE	ΟE	Mode	I/O1toI/O8	Supply current
Н	*	*	*	Standby	High impedance	Standby (IsB)
*	L	*	*	Standby	High impedance	Standby (IsB)
L	Н	L	*	Write	Data input	Active (Icc)
L	Н	Н	L	Read	Data output	Active (Icc)
L	Н	Н	Н	Output disable	High impedance	Active (Icc)

(*=Don't Care, L=Low, H=High)







5. Absolute Maximum Ratings

Parameter	Symbol	Ratings ·	Unit
Supply voltage (*1)	Vcc	-0.3 to $+7.0$	V
Input voltage (*1)	Vın	-0.3(*2)to Vcc+0.3	V
Operating temperature	Topr	-10 to $+70$	r
Storage temperature	Tstg	-65 to $+150$	°C

Note) *1. The maximum applicable voltage on any pin with respect to GND.

*2. Undershoot of -3.0V is allowed width of pluse bellow 50ns.

6. Recommended DC Operating Conditions

$$(Ta=-1 \ 0\%to + 7 \ 0\%)$$

Parameter	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	Vcc	4.5	5.0	5.5	V
Input voltage	VIH	2.2		Vcc+0.3	V
	VIL	-0.3 (*3)		0.8	V

Note) *3. Undershoot of -3.0V is allowed width of pluse below 50ns.

7. DC Electrical Characteristics

$$(Ta = -1 \ 0 \ Cto + 7 \ 0 \ C, Vcc = 5 \ V \pm 1 \ 0 \ \%)$$

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Input leakage	ILI	V _{IN} =OV to V _{CC}	Address of the Control of the Contro				
current				-1.0		1.0	μΑ
Output	ILO	CE1=VIR or CE2=VIL or					
leakage		OE=VIH OF WE=VIL		-1.0		1.0	μΑ
current		V _{1/0} =OV to Vcc					
Operating	Icc	CE1=VIL, VIN=VIL Or VIH	t cycle	***************************************			
supply		CE2=V1H, I1/0=OmA	=100ns			4 5	m A
current	Iccı	CE1=0. 2V, Vin=0. 2V or Vcc - 0. 2V	tcycle				
		CE ₂ =V _{CC} - O. 2V, I _{1/0} =OmA	=1.0 μ s			1 0	m A
Standby	Іѕв	$\overline{CE_1}$, $CE_2 \ge V_{cc} - 0$. 2V or $CE_2 \le 0$. 2V				1.0	μΑ
current	Isbı	CE1,=V111 or CE2=V1L	AND THE PROPERTY OF THE PROPER			5	m A
Output	Vol	IoL= 2.1mA				0.4	V
voltage	Vон	Ion=-1. OmA		2.4			V



8. AC Electrical Characteristics

AC Test Conditions

Input pulse level	0.6 V to 2.4	V
Input rise and fall time	1 0	n s
Input and Output timing Ref. level	1.5	V
Output load	$1 T T L + C_L (1 0 0 pF)$	(*4)

Note) *4. Including scope and jig capacitance.

Read cycle

$$(Ta = -1 \ 0\%to + 7 \ 0 \ \%, Vcc = 5 \ V \pm 1 \ 0\%)$$

Parameter	Symbol	Min.	Тур.	Max.	Unit
Read cycle time	t RC	100			ns
Address access time	t a a			100	ns
CE ₁ access time	t ACE1			100	ns
CE2 access time	t ACE 2			100	ns
Output enable to output valid	toe			4 0	ns
Output hold from address change	tон	1 0			ns
CE ₁ Low to output active	t L Z 1	1 0			ns
CE ₂ High to output active	t LZ2	1 0			ns
OE Low to output active	tolz	5			ns
CE: High to output in High impedance	t HZI	0	•	3 0	ns
CE2 Low to output in High impedance	t HZ2	0		3 0	ns
OE High to output in High impedance	tонz	0		2 0	ns

Write cycle

$$(Ta = -1 \ 0\%to + 7 \ 0\%, Vcc = 5 \ V \pm 1 \ 0\%)$$

Parameter	Symbol	Min.	Тур.	Max.	Unit
Write cycle time	t wc	1 0 0			ns
CE ₁ Low to end of write	t cw1	8 0	100000000000000000000000000000000000000		ns
CE ₂ High to end of write	t cw2	8 0	AAAAAAAAAAAAA		ns
Address valid to end of write	t aw	8 0			ns
Address setup time	tas	0			ns
Write pluse width	t wp	6 0			ns
Write recovery time	twr	0	THE RESIDENCE OF THE PARTY OF T		ns
Input data setup time	t DW	4 0			ns
Input data hold time	t DH	0			ns
WE High to output active	tow	1 0			ns
WE Low to output in High impedance	t wz	0		3 0	ns
OE High to output in High impedance	tонz	0		2 0	ns

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9. Data Retention Characteristics

(Ta=-10 C to+70 C)

Paramenter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Data Retention	Vccdr	C E 2 ≤ 0. 2 V or					
supply voltage		$\overline{CE}_1 \ge V_{CCDR} - 0.2$	V (*5)	2.0		5.5	V
Data Retention	I ccdr	$V_{CCDR} = 3 V$	T a = 2 5 ℃			0.2	μΑ
supply current		$C E_2 \leq 0.2$ or	T a = 4 0 ℃			0.4	μΑ
		$\overline{CE}_1 \ge V_{CCDR} - 0.2$	V (*5)			0.6	μΑ
Chip enable	t cdr						
setup time				0			ns
Chip enable	t R			(*6)			
hold time				trc			ns

Note) *5. $C E_2 \ge V_{CCDR} - 0.2 V$ or $C E_2 \le 0.2 V$ *6. Read Cycle

10. Pin Capacitance

 $(Ta = 25 \, \text{C}, \quad f = 1 \, \text{MHz})$

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input capacitance	Cin	$V_{IN} = 0 V$			7	рF	* 7
I/O capacitance	C1/0-	$V_{1/0} = 0 V$			1 0	рF	* 7

Note) *7. This parameter is sampled and not production tested.



11. Timing Chart Read cycle timing chart— (*8) trc Addresstaa t aceı CEI t LZI> t HZ 1 $C E_2$ t HZ2 t ace 2 t o e ΟE tonz t olz Data Valid Dour Note) *8. WE is high for Read cycle. Write cycle timing chart— (OE Controlled) t wc Address **(*12)** ΟE $t\ _{\text{A}\text{W}}$ $t \ cw$ CE 1 **(***10) tcw $C E_2$ **(***10) tas $t w_P$ t wr. (*11) **(***9) WE t онz (*14) Dour t Dw $t\,\mathrm{DH}$ **(***13) DIN Data Valid



DIN

Write cycle timing chart— (OE Low fixed) t wc Address taw (*12) tcw CE 1 **(*10)** t cw (*10) CE2 tas t w P (*11) **(*9)** WE tow (*14) (*15)Dour

Note) * 9. A write occurs during the overlap of a low $\overline{\text{CE}_1}$, a high CE_2 and a low $\overline{\text{WE}}$, A write begins at the latest transition among $\overline{\text{CE}_1}$ going low, CE_2 going high and $\overline{\text{WE}}$ going low.

A write ends at the earliest transition among $\overline{CE_1}$ going high, CE_2 going low and \overline{WE} going high. twp is measured from the beginning of write to the end of write.

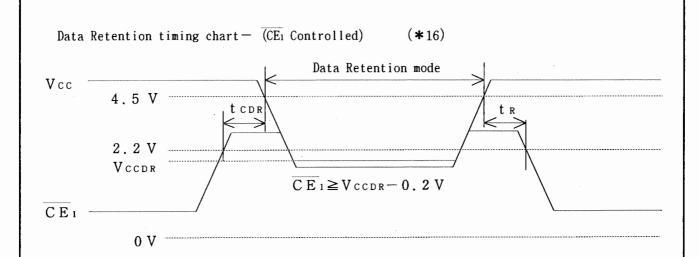
(*13)

Data

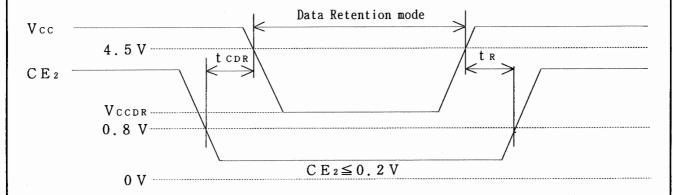
Valid

- * 10. tow is measured from the later of $\overline{CE_1}$ going low or CE_2 going high to the end of write.
- * 11. this is measured from the address valid to the beginning of write.
- * 12. twx is measured from the end of write to the address change, twx1 applies in case a write ends at $\overline{CE_1}$ or \overline{WE} going high, twx2 applies in case a write ends at CE_2 going low.
- * 13. During this period, I/O pins are in the output state, therefore the input signals of opposite phase to the outputs must not be applied.
- * 14. If $\overline{CE_1}$ goes low simultaneously with \overline{WE} going low or after \overline{WE} going low, the outputs remain in high impedance state.
- * 15. If $\overline{CE_1}$ goes high simultaneously with \overline{WE} going high or before \overline{WE} going high, the outputs remain in high impedance state.





Data Retention timing chart— (CE2 Controlled)



Note) *15. To control the data retention mode at CE₁, fix the input level of CE₂ between VCCDR and VCCDR -0.2V or OV and 0.2V during the data retention mode.



12 Package and packing specification

[Applicability]

This specification applies to IC package of the LEAD-FREE delivered as a standard specification.

1. Storage Conditions.

- Normal temperature : 5~40°C
- · Normal humidity: 80%(Relative humidity) max.
 - "Humidity" means "Relative humidity"

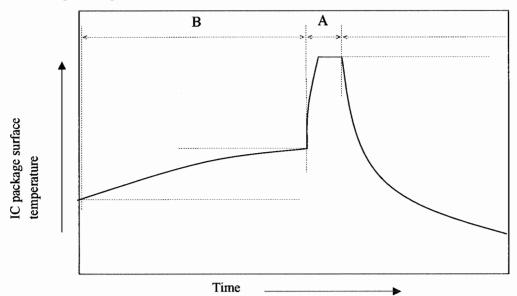
2. Baking Condition.

Baking is no necessity.

3. Mounting conditions.

Please mount the ICs as follows in order to prevent the IC quality deteriorating.

- 1-1. Soldering conditions. (The following conditions apply only to one-time soldering.)
- (1) Solder dipping. (one-time dipping only)
 - · Temperature and period :
 - A) Peak temperature. 260°C max. for 10 seconds Max.
 - B) Preheat temperature of 120 to 150°C for 120±60 seconds
 - · Measuring point:
 - A) Solder bath.
 - B) IC package surface.
 - · Temperature profile:



(2) Manual soldering (soldering iron) (one-time soldering only)

Soldering iron should only touch the IC's outer leads.

· Temperature and period:

350℃ max. for 3 seconds / pin max.

(Soldering iron should only touch the IC's outer leads.)

- · Measuring point : Soldering iron tip.
- 4. Condition for removal of residual flux.
 - (1) Ultrasonic washing power: 25 watts / liter max.
 - (2) Washing time: Total 1 minute max.
 - (3) Solvent temperature: 15~40℃



5. Package outline specification.

Refer to the attached drawing.

(Plastic body dimensions do not include burr of resin.)

The contents of LEAD-FREE TYPE application of the specifications. (*2)

6. Markings.

6-1. Marking details. (The information on the package should be given as follows.)

(1) Product name : LH5164A-10LF

(2) Company name : SHARP

(3) Date code : (Example) YYWW XXX

YY \rightarrow Denotes the production year. (Last two digits of the year.) WW \rightarrow Denotes the production week. $(01 \cdot 02 \cdot \sim \cdot 52 \cdot 53)$

XXX \rightarrow Denotes the production ref. code (1 \sim 3 digits).

(4) "JAPAN" indicates the country of origin.

6-2. Marking layout.

The layout is shown in the attached drawing.

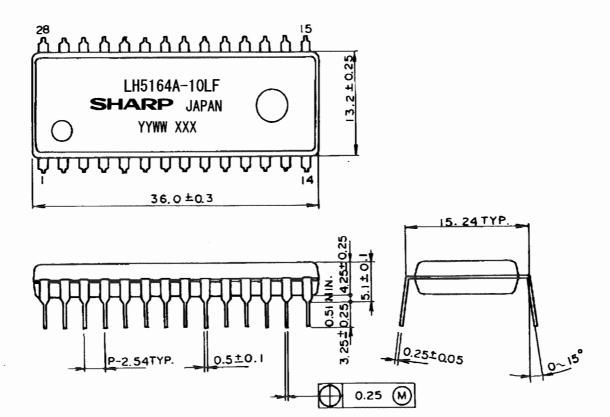
(However, this layout does not specify the size of the marking character and marking position.)

*2 The contents of LEAD-FREE TYPE application of the specifications.

LEAD FINISH or BALL TYPE	LEAD-FREE TYPE (Sn-Bi)	
DATE CODE	They are those with an underline.	
The word of "LEAD FREE" is printed on the packing label	Printed	



(Note) It is those with an underline printing in a date code because of a LEAD-FREE type.



DIP028-P-0600-AA852

LEAD FI		INISH	LEAD MATERIAL			
LEAD T	YPE		Sn-Bi PL	ATING	42Alloy	
NAME	DIP028-P	-0600		NOTE : Plastic body dime	nsions do not include burr of resin.	
DRAWING NO.	AA852	UNIT	mm			



7. Packing specifications.

7-1. Packing materials.

Material name	Material specifications	Purpose
Magazine	Anti-static treated plastic (15 devices/magazine)	Packing of devices.
Stopper	Plastic or rubber	Securing of devices.
Label	Paper (1piece/inner carton)	Indication of product name, quantity and packed date.
Inner carton	Cardboard (600 devices/carton max.)	Packing the magazines.
Outer carton	Cardboard (2400 devices/carton max.)	Outer packing.

(Devices must be inserted into the magazine in the same direction.)

7-2. Outline dimension of magazine.

Refer to the attached drawing.

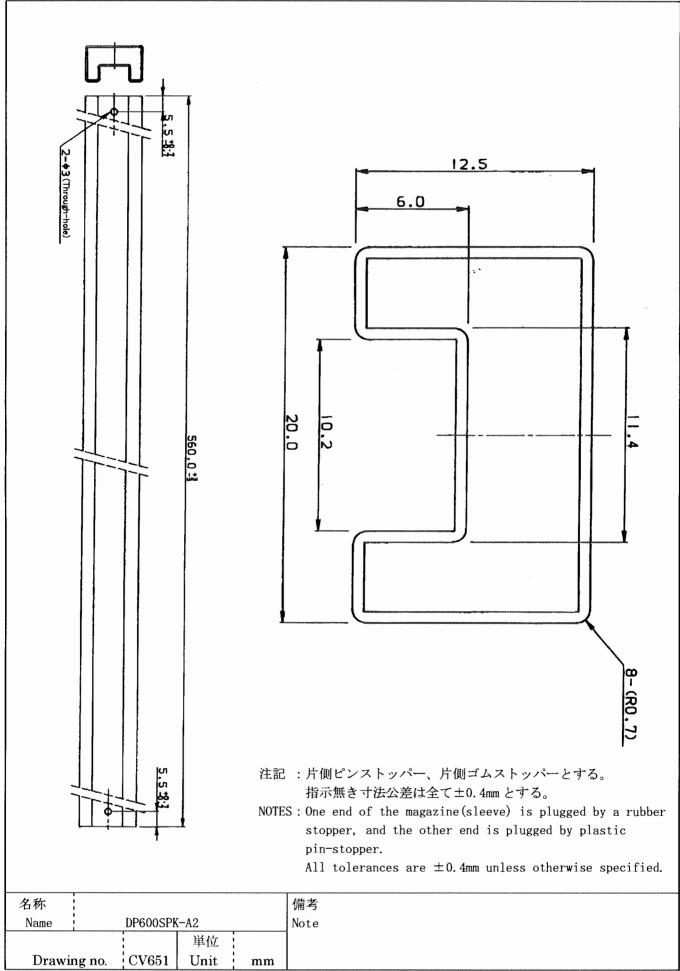
7-3. Outline dimension of carton.

Refer to the attached drawing.

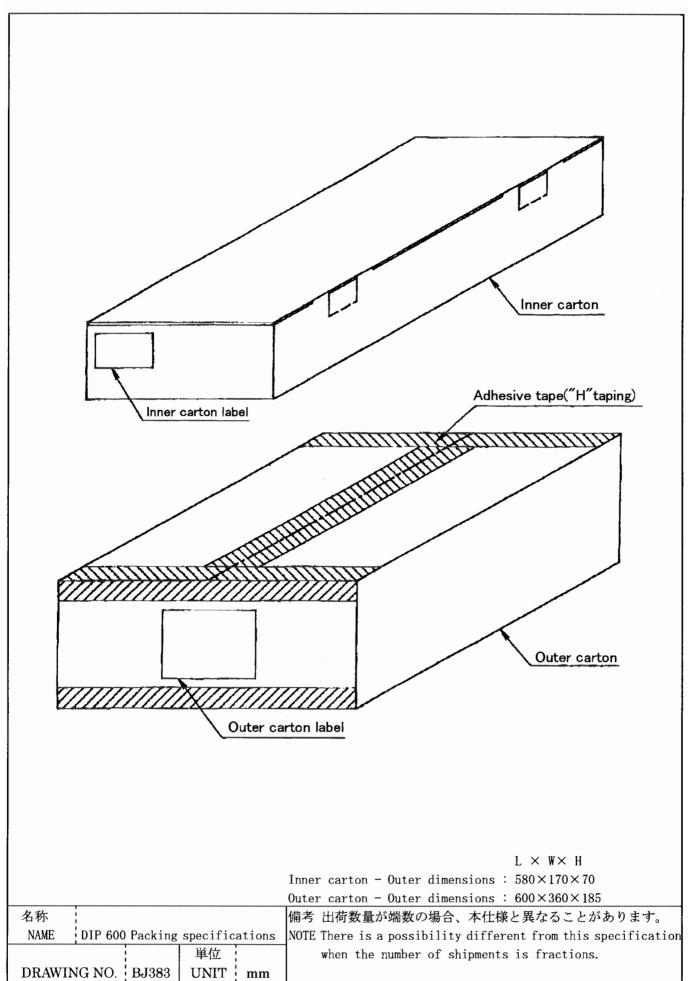
8. Precautions for use.

- (1) Opening must be done on an anti-ESD treated workbench.
 All workers must also have undergone anti-ESD treatment.
- (2) The magazines have undergone anti-ESD treatment.
- (3) Be sure to fit stoppers to both ends of the magazine when storing to prevent the devices from slipping out.
- (4) The devices should be stored at a temperature of $5\sim35$ °C (normal temperature) and maximum relative humidity of 75%, and should be mounted within one year of the date of delivery.

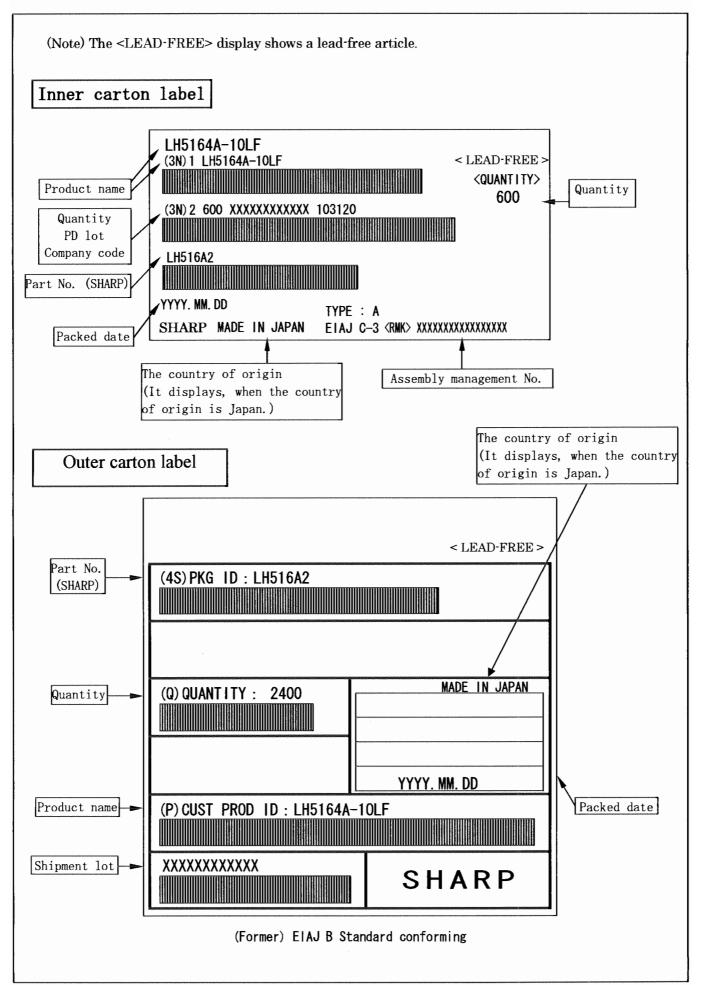












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